CM2006



VGA Port Companion Circuit For Monitors

Features

- Includes ESD protection, level-shifting, buffering and sync impedance matching
- VESA VSIS Version 1 Revision 2 Compatible Inter-
- Supports Optional NAVI Signalling requirements
- 7 channels of ESD protection for all VGA port connector pins meeting IEC-61000-4-2 Level 4 ESD requirements (±8kV contact discharge)
- Very low loading capacitance from ESD protection diodes on VIDEO lines, 3pF maximum
- Schmitt triggered input buffers for HSYNC and **VSYNC** lines
- Bi-directional level shifting N-channel FETs provided for DDC_CLK & DDC_DATA channels
- Backdrive protection on all lines
- Compact 16-lead QSOP package

Applications

- VGA and DVI-I ports in:
 - Monitors
 - Set Top Boxes

Product Description

The CM2006 connects between the VGA or DVI-I port connector and the internal analog or digital flat panel controller logic. The CM2006 incorporates ESD protection for all signals, level shifting for the DDC signals and buffering for the SYNC signals. ESD protection for the video, DDC and SYNC lines is implemented with low-capacitance current steering diodes.

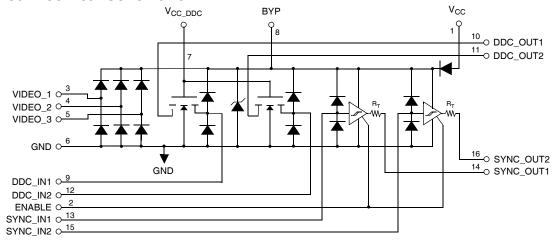
All connector interface pins are designed to safely handle the high current spikes specified by IEC-61000-4-2 Level 4 (±8kV contact discharge). The ESD protection for the DDC, SYNC and VIDEO signal pins is designed to prevent "back current" when the device is powered down while connected to a video source that is powered up.

Separate positive supply rails are provided for the VIDEO / SYNC signals and DDC signals to facilitate interfacing with low voltage video controller ICs and microcontrollers to provide design flexibility in multisupply-voltage environments.

Two Schmitt-Triggered non-inverting buffers redrive and condition the HSYNC and VSYNC signals from the video Connector (SYNC1, SYNC2). These buffers accept VESA VSIS compliant TTL input signals and convert them to CMOS output levels that swing between Ground and V_{CC}.

(cont'd next page)

Simplified Electrical Schematic



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Product Description (cont'd)

Two N-channel MOSFETs provide the level shifting function required when the DDC controller or EDID EEPROM is operated at a lower supply voltage than the monitor. The gate terminals for these MOSFETS (V_{CC_DDC}) should be connected to the supply rail (typically 3.3V, 2.5V etc.) that supplies power to the transceivers of the DDC controller.

PACKAGE / PINOUT DIAGRAM						
	Top View					
	V _{CC}	16 SYNC_OUT2 15 SYNC_IN2 14 SYNC_OUT1				
	VIDEO_2	13 SYNC_IN1 12 DDC_IN2				
	GND	11				
Note: This drawing is not to scale.	16 F	Pin QSOP				

PIN DESCRIPTIONS					
LEAD(s)	NAME	DESCRIPTION			
1	V _{CC}	This is a supply input for the SYNC_1 and SYNC_2 level shifters, video protection and the DDC circuits.			
2	ENABLE	Active high enable. Disables the Sync buffer outputs when low.			
3	VIDEO_1	Video signal ESD protection channel. This pin is typically tied one of the video lines between the controller device and the video connector.			
4	VIDEO_2	Video signal ESD protection channel. This pin is typically tied one of the video lines between the controller device and the video connector.			
5	VIDEO_3	Video signal ESD protection channel. This pin is typically tied one of the video lines between the controller device and the video connector.			
6	GND	Ground reference supply pin.			
7	V _{CC_DDC}	This is an isolated supply input for the DDC_1 and DDC_2 level-shifting N-FET gates.			
8	BYP	An external 0.22uF bypass capacitor is required on this pin.			
9	DDC_IN1	DDC signal input. Connects to the video connector side of one of the DDC lines.signal output.			
10	DDC_OUT1	DDC signal output. Connects to the monitor DDC logic.			
11	DDC_OUT	DDC signal output. Connects to the monitor DDC logic.			
12	DDC_IN2	DDC signal input. Connects to the video connector side of one of the DDC lines			
13	SYNC_IN1	Sync signal buffer input. Connects to the video connector side of one of the sync lines.			
14	SYNC_OUT1	Sync signal buffer output. Connects to the monitor SYNC logic.			
15	SYNC_IN2	Sync signal buffer input. Connects to the video connector side of one of the sync lines.			
16	SYNC_OUT2	Sync signal buffer output. Connects to the monitor SYNC logic.			



Ordering Information

PART NUMBERING INFORMATION					
		Standard Finish			ee Finish
		Ordering Part		Ordering Part	
Pins	Package	Number ¹	Part Marking	Number ¹	Part Marking
16	QSOP	CM2006-02QS	CM2006-02QS	CM2006-02QR	CM2006-02QR

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

Specifications

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	RATING	UNITS			
V _{CC_DDC} and V _{CC} Supply Voltage Inputs	[GND - 0.5] to +6.0	V			
DC Voltage at Inputs VIDEO_1, VIDEO_2, VIDEO_3 DDC_IN1, DDC_IN2 DDC_OUT1, DDC_OUT2 SYNC_IN1, SYNC_IN2, ENABLE	[GND - 0.5] to [V _{CC} + 0.5] [GND - 0.5] to 6.0 [GND - 0.5] to 6.0 [GND - 0.5] to [V _{CC} + 0.5]	V V V			
Operating Temperature Range	-40 to +85	°C			
Storage Temperature Range	-40 to +150	°C			
Package Power Rating (T _A =25°C)	500	mW			

STANDARD OPERATING CONDITIONS					
PARAMETER	RATING	UNITS			
Operating Temperature Range	-40 to +85	°C			
V _{CC}	5	V			



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Specifications

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	ELECTRICAL OPERATING CHARACTERISTICS (SEE NOTE 1)						
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{CC_DDC}	V _{CC_DDC} Supply Current	V _{CC_DDC} = 5.0V			10	μΑ
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{CC}	V _{CC} Supply Current	V _{CC} = 5V; SYNC inputs at GND or V _{CC} ;			1	mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			SYNC outputs unloaded				
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			1 00			2.0	mA
$V_{III} \text{Logic High Input Voltage} \qquad V_{CC} = 5.0V; \text{ Note 2} \qquad 2.0 \qquad V$ $V_{III} \text{Logic Low Input Voltage} \qquad V_{CC} = 5.0V; \text{ Note 2} \qquad 0.5 V$ $V_{HYS} \text{Hysteresis Voltage} \qquad V_{CC} = 5.0V; \text{ Note 2} \qquad 400 \qquad \text{mV}$ $V_{OH} \text{Logic High Output Voltage} \qquad V_{CC} = 5.0V; \text{ Note 2} \qquad 4.0 \qquad V$ $V_{OH} \text{Logic Low Output Voltage} \qquad I_{OH} = 0\text{mA}, V_{CC} = 5.0V; \text{ Note 2} \qquad 4.0 \qquad V$ $V_{OL} \text{Logic Low Output Voltage} \qquad I_{OL} = 0\text{mA}, V_{CC} = 5.0V; \text{ Note 2} \qquad 4.0 \qquad V$ $V_{OL} \text{Logic Low Output Resistance} \qquad V_{CC} = 5.0V; \text{ Note 2} \qquad 0.15 V$ $P_{OUT} \text{SYNC Driver Output Resistance} \qquad V_{CC} = 5.0V; \text{ SYNC Inputs at GND or 3.0V} \qquad 7 15 24 \Omega$ $I_{IN} \text{Input Current} \qquad V_{IDEO Inputs} \qquad V_{CC} = 5.0V; V_{IN} = V_{CC} \text{ or GND} \qquad 15 10 \mu A$ $I_{OFF} \text{Level Shifting N-MOSFET "OFF" State} \qquad (V_{CC} = 5.0V; V_{IN} = V_{CC} \text{ or GND} \qquad 10 \mu A$ $I_{BACKDRIVE} \text{SUBC Driver Output Resistance} \qquad V_{CC} = 5.0V; V_{IN} = V_{CC} \text{ or GND} \qquad 10 \mu A$ $I_{BACKDRIVE} \text{Current conducted from input pins when Vcc} \text{(VCC_DDC} \cdot V_{DDC_OUT}) < 0.4V; V_{DDC_OUT} = V_{CC_DDC} \qquad 10 \mu A$ $V_{ON} \text{Voltage Drop Across Level-shifting} V_{CC_DDC} = 2.5V; V_S = \text{GND}; I_{DS} = 3\text{mA}; \qquad 0.18 V$ $V_{CC_DDC} \cdot V_{DDC_OUT} = 0.5V; V_{IN} = 0.5V; V_{I$							
$\begin{array}{c} V_{IL} \\ V_{IL} \\ V_{IL} \\ V_{OL} \\ V_{OL$	•		'			1.0	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V _{IH}	Logic High Input Voltage	00 1	2.0			V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V_{IL}	Logic Low Input Voltage	V _{CC} = 5.0V; Note 2			0.5	V
$\begin{array}{c} V_{OL} & \text{Logic Low Output Voltage} & I_{OL} = \text{OmA}, V_{CC} = 5.0\text{V}; \text{ Note 2} \\ \hline \\ R_{OUT} & \text{SYNC Driver Output Resistance} & V_{CC} = 5.0\text{V}; \text{SYNC Inputs at GND or } 3.0\text{V} \\ \hline \\ I_{IN} & \text{Input Current} & V_{IDEO Inputs} & V_{CC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 5.0\text{V}; V_{IN} = V_{CC} \text{ or GND} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DDC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DC_IN} > 0.4\text{V}; V_{DDC_IN} = V_{CC_DDC} \\ \hline \\ V_{OC} = 0.0\text{V}; V_{DC} = 0.0\text{V}; V_{DC} = 0.0\text{V}; V_{DC_IN} =$	V_{HYS}	Hysteresis Voltage	V _{CC} = 5.0V; Note 2		400		mV
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V_{OH}	Logic High Output Voltage	$I_{OH} = 0mA, V_{CC} = 5.0V; Note 2$	4.0			V
$ \begin{array}{c} I_{IN} \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\$	V _{OL}	Logic Low Output Voltage	I _{OL} = 0mA, V _{CC} = 5.0V; Note 2			0.15	V
$\begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \end{array} \end{array} \end{array} \end{array} \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \begin{array}{c} & \\ & \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \end{array} \end{array} \begin{array}{c} & \\ & \\ & \end{array} \begin{array}{c} & \\ & \\ & \end{array} \begin{array}{c} & & \\ & \\ & \end{array} \begin{array}{c} & \\ & \\ & \end{array} \begin{array}{c} & \\ & \\ & \end{array} \begin{array}{c} & \\ & \\ & \end{array} \begin{array}{$	R _{OUT}	SYNC Driver Output Resistance	V _{CC} = 5.0V; SYNC Inputs at GND or 3.0V	7	15	24	Ω
$ \begin{array}{c} I_{OFF} \\ I_{DFF} \\ I_{DEC} $	I _{IN}	· ·	V _{CC} = 5.0V; V _{IN} = V _{CC} or GND			±10	μА
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		SYNC_IN1, SYNC_IN2 Inputs	$V_{CC} = 5.0V$; $V_{IN} = V_{CC}$ or GND			±10	μΑ
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{OFF}		$(V_{CC_DDC} - V_{DDC_IN}) < 0.4V; V_{DDC_OUT} = V_{CC_DDC}$			10	μΑ
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Leakage Current	$(V_{CC_DDC} - V_{DDC_OUT}) < 0.4V; V_{DDC_IN} = V_{CC_DDC}$			10	μΑ
$\begin{array}{c} \text{N-MOSFET when "ON"} \\ \hline \\ C_{\text{IN_VID}} \\ \hline \\ V\text{IDEO Input Capacitance} \\ \hline \\ V_{\text{CC}} = 5.0\text{V}; \ V_{\text{IN}} = 2.5\text{V}; \ f = 1\text{MHz}; \ \text{Note 4} \\ \hline \\ V_{\text{CC}} = 2.5\text{V}; \ V_{\text{IN}} = 1.25\text{V}; \ f = 1\text{MHz}; \ \text{Note 4} \\ \hline \\ V_{\text{CC}} = 2.5\text{V}; \ V_{\text{IN}} = 1.25\text{V}; \ f = 1\text{MHz}; \ \text{Note 4} \\ \hline \\ V_{\text{CC}} = 2.5\text{V}; \ V_{\text{IN}} = 1.25\text{V}; \ f = 1\text{MHz}; \ \text{Note 4} \\ \hline \\ V_{\text{CC}} = 2.5\text{V}; \ V_{\text{IN}} = 1.25\text{V}; \ f = 1\text{MHz}; \ \text{Note 4} \\ \hline \\ V_{\text{CC}} = 5.0\text{V}; \ \text{Input t} \ t_{\text{R}} \ \text{and t} \ t_{\text{F}} < 5\text{ns} \\ \hline \\ V_{\text{ESD}} = 12 \\ \hline \\ V_{\text{ESD}} = $	I _{BACKDRIVE}		V _{CC} < V _{INPUT_PIN} , Note 6		10		μА
$V_{CC} = 2.5V; \ V_{IN} = 1.25V; \ f = 1 \text{MHz}; \ \text{Note 4} \\ V_{CC} = 2.5V; \ V_{IN} = 1.25V; \ f = 1 \text{MHz}; \ \text{Note 4} \\ V_{CC} = 2.5V; \ V_{IN} = 1.25V; \ f = 1 \text{MHz}; \ \text{Note 4} \\ V_{CC} = 5.0V; \ \text{Input t}_{R} \ \text{and t}_{F} < 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{R} \ \text{and t}_{F} < 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{R} \ \text{and t}_{F} < 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{R} \ \text{and t}_{F} < 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{R} \ \text{and t}_{F} < 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{R} \ \text{and t}_{C} < 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{R} \ \text{and t}_{C} < 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{CC} = 5.0V; \ \text{Input t}_{CC} = 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{CC} = 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{CC} = 5 \text{ns} \\ V_{CC} = 5.0V; \ \text{Input t}_{CC} = 5 \text{ns} \\ V_{CC} = 5 \text{ns} \\ V$	V _{ON}	, ,	$V_{CC_DDC} = 2.5V$; $V_S = GND$; $I_{DS} = 3mA$;			0.18	V
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	C _{IN_VID}	VIDEO Input Capacitance	V _{CC} = 5.0V; V _{IN} = 2.5V; f = 1MHz; Note 4			3	pF
$\begin{array}{cccccccccccccccccccccccccccccccccccc$			V _{CC} = 2.5V; V _{IN} = 1.25V; f = 1MHz; Note 4			3.5	pF
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	t _{PLH}	SYNC Driver L => H Propagation Delay	$C_L = 50pF; V_{CC} = 5.0V; Input t_R and t_F < 5ns$			12	ns
V_{ESD1} ESD Withstand Voltage, Sync_out pins only V_{CC} = 5V; Notes 3, 4, & 5 ± 2 kV	t _{PHL}	SYNC Driver H => L Propagation Delay	$C_L = 50pF; V_{CC} = 5.0V; Input t_R and t_F < 5ns$			12	ns
	t _{R,} t _F	SYNC Driver Output Rise & Fall Times	$C_L = 50pF$; $V_{CC} = 5.0V$; Input t_R and $t_F < 5ns$		3		ns
	V _{ESD1}	ESD Withstand Voltage, Sync_out pins only	V _{CC} = 5V; Notes 3, 4, & 5	± 2			kV
		ESD Withstand Voltage	V _{CC} = 5V; Notes 3, 4, & 6	± 8			kV

- Note 1: All parameters specified over standard operating conditions unless otherwise noted
- Note 2: These parameters apply only to the SYNC drivers. Note that $R_{OUT} = R_T + R_{BUFFER}$.
- Note 3: Per the IEC-61000-4-2 International ESD Standard, Level 4 contact discharge method. BYP and V_{CC} must be bypassed to GND via a low impedance ground plane with a 0.22 µF, low inductance, chip ceramic capacitor at each supply pin. ESD pulse is applied between the applicable pins and GND. ESD pulses can be positive or negative with respect to GND. Applicable pins are: VIDEO_1, VIDEO_2, VIDEO_3, SYNC_IN1, SYNC_IN2, DDC_IN1 and DDC_IN2. All pins are ESD protected to the industry standard ±2kV Human Body Model (MIL-STD-883, Method 3015).
- Note 4: This parameter is guaranteed by design and characterization.
- Note 5: This specification applies to the SYNC_OUT pins only.
- Note 6: Applicable pins are: VIDEO_1, VIDEO_2, VIDEO_3, SYNC_IN1, SYNC_IN2, DDC_IN1 and DDC_IN2.



Application Information

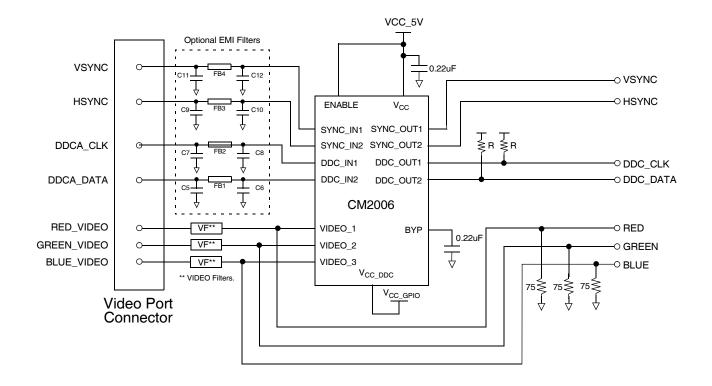


Figure 1. Typical Application Connection Diagram

NOTES

- The CM2006 should be placed as close to the VGA or DVI-I connector as possible.
- The ESD protection channels VIDEO 1, VIDEO 2, VIDEO 3 may be used interchangeably between the R, G, B signals. 2
- If differential video signal routing is used, the RED, BLUE, and GREEN signal lines should be terminated with external 37.5 3 ohm resistors.
- "VF" are external video filters for the RGB signals. 4
- Supply bypass capacitors C1 and C2 must be placed immediately adjacent to the corresponding Vcc pins. Connections to the Vcc pins and ground plane must be made with minimal length copper traces (preferably less than 5mm) for best ESD protection.
- The bypass capacitor for the BYP pin has been omitted in this diagram. This results in a reduction in the maximum ESD withstand voltage at the DDC_OUT pins from ±8kV to ±2kV. If 8kV ESD protection is required, a 0.22µF ceramic bypass capacitor should be connected between BYP and ground.
- The SYNC buffers may be used interchangeably between HSYNC and VSYNC.
- The EMI filters at the SYNC OUT and DDC OUT pins (C5 to C12, and Ferrite Beads FB1 to FB4) are for reference only. The component values and filter configuration may be changed to suit the application.
- The DDC level shifters DDC_IN, DDC_OUT, may be used interchangeably between DDCA_CLK and DDCA_DATA.
- 10 R1, R2 are optional. They may be used, if required, to pull the DDC_CLK and DDC_DATA lines to VCC_5V when no monitor is connected to the VGA connector. If used, it should be noted that "back current" may flow between the DDC pins and VCC_5V via these resistors when VCC_5V is powered down.

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Mechanical Details

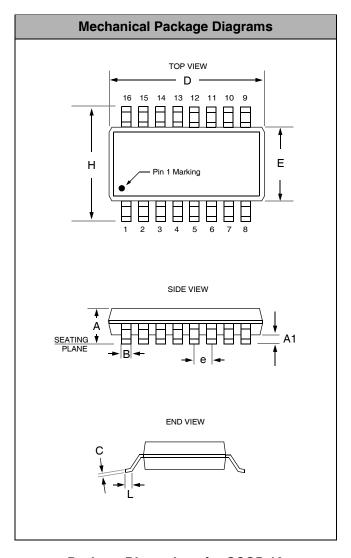
QSOP Mechanical Specifications

CM2006 devices are packaged in 16-pin QSOP packages. Dimensions are presented below.

For complete information on the QSOP-16 package, see the California Micro Devices QSOP Package Information document.

PACKAGE DIMENSIONS						
Package	QS	OP (JEDEC	name is S	SOP)		
Pins		1	16			
Dimensions	Millimeters		Inches			
Difficusions	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A1	0.10 0.25 0.004 0					
В	0.20	0.012				
С	0.18 0.25 0.007		0.007	0.010		
D	4.80	5.00	0.189	0.197		
E	3.81	3.98	0.150	0.157		
е	0.64 BSC 0.025 BSC					
Н	5.79 6.19 0.228 0.24					
L	0.40	1.27	0.016	0.050		
# per tube	100 pcs*					
# per tape and reel	2500 pcs					
Controlling dimension: inches						

^{*} This is an approximate number which may vary.



Package Dimensions for QSOP-16